## DOCKET NO. PHQ99.010

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: J.A. De Coster et al.

Examiner: Guerrero

Application No.: 09/807,067

Art Unit: 2822

Filed: April 6, 2001

For: METHOD OF MANUFACTURING AN INTEGRATED CIRCUIT COMPRISING

AN IMPROVED SILICIDATION AND A CORRESPONDING INTEGRATED

CIRCUIT

Box AF Commissioner for Patents Washington D.C. 20231

**FAX RECEIVED** 

JAN 2 8 2003

## **RULE 116 AMENDMENT**

**TECHNOLOGY CENTER 2800** 

Sir:

In response to the Final Office Action of December 17, 2002, Applicants respectfully request that the above-identified application be reconsidered in view of the amendments and remarks that follow, and that the application be passed to issue.

## In the Claims

Please amend the claims as follows:



1. (TWICE AMENDED) A method of manufacturing an integrated circuit, which method includes a stage wherein lateral isolation regions (spacers) are formed at the sides of a projecting polysilicon region so as to be in contact therewith, said lateral isolation regions each being composed of a smaller isolation layer (402) that is formed by depositing an

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